

**Supporting Information for**

# Tunable hysteresis effect for perovskite solar cells

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## Experiment

### Materials

Unless stated otherwise, all materials were purchased from Sigma-Aldrich or Acros Organics and used as received.  $\text{CH}_3\text{NH}_3\text{I}$  was synthesized and purified according to literature procedures<sup>1</sup>. The perovskite precursor solution was prepared by dissolving 573.0 mg  $\text{PbI}_2$ , 197.5 mg  $\text{CH}_3\text{NH}_3\text{I}$  and 13.70 mg 5-AVAI in 1.0 ml  $\gamma$ -butyrolactone (GBL), and stirred at 70 °C for 30 min. The  $\text{TiO}_2$ ,  $\text{ZrO}_2$  and carbon pastes were prepared as previously reported<sup>2, 3</sup>.

### Device fabrication.

Unless stated otherwise, the whole device fabrication process was carried out under ambient conditions (RH25-35%). The FTO-coated glass substrates (Tec15, Pilkington) were first etched by laser and cleaned by ultrasonication with detergent, deionized water, acetone and ethanol. The c- $\text{TiO}_2$  layer was then deposited on the patterned substrates by aerosol spray pyrolysis as follow: The patterned FTO substrate was placed on a hotplate with a mask, as shown in Figure S1, and heated up to 450 °C. A titanium diisopropoxide bis(acetylacetonate) solution was diluted in ethanol (1:39, volume ratio), and kept in a glass sprayer which was purchased from Sigma-Aldrich. The distance between the sprayer and the hotplate was ~10 cm, and the spraying angle was 60-70 degree. The carrier gas was oxygen with a flow rate of ~10 ml/s. The sprayer moved at a speed of ~10 cm/s, along the red line marked spraying path in Figure S1. After spraying, the c- $\text{TiO}_2$  coated FTO substrate was sintered at 450 °C for 30 min. After cooling to room temperature (RT, 25 °C), a 1  $\mu\text{m}$ -thick mesoporous  $\text{TiO}_2$  layer, a 2  $\mu\text{m}$ -thick  $\text{ZrO}_2$  spacer layer and a 10  $\mu\text{m}$ -thick carbon layer were screen-printed on the substrates layer by layer. The  $\text{TiO}_2$  layer and  $\text{ZrO}_2$  layer were sintered at 450 °C for 30 min, and the carbon layer was sintered at 400 °C for 30 min, forming the mesoporous triple-layer based scaffold. After cooling to room temperature, the perovskite precursor solution was infiltrated by drop casting *via* the top of the carbon layer. After drying at 50 °C for one hour, the printable mesoscopic PSCs were obtained.

## Characterization

The thickness of the films was measured by a profilometer (DektakXT, Bruker). The atomic force microscope (AFM) measurements were performed on SPM9700 (Shimadzu). Photocurrent-density voltage ( $J$ - $V$ ) curves were characterized with a Keithley 2400 source meter and a Newport solar simulator (model 91192). The power of the simulated light was calibrated to  $100 \text{ mW cm}^{-2}$  using a Newport Oriel PV reference cell (model 91150V). The active area of the device is about  $0.8 \text{ cm}^2$  and a black mask with a circular aperture ( $0.126 \text{ cm}^2$ ) was applied for  $J$ - $V$  measurements. The  $J$ - $V$  testing was performed with forward and backward scan directions at a scan rate of  $250 \text{ mV s}^{-1}$ ,  $100 \text{ mV s}^{-1}$ ,  $50 \text{ mV s}^{-1}$ , and  $25 \text{ mV s}^{-1}$  (sweep delay time of 100 ms). Before  $J$ - $V$  scans, the devices were usually subjected to the simulate sun light for several minutes. All the measurements were carried out at RH25-35% and room temperature.

**Table S1** Dependence of hysteresis effect on spraying cycles of c-TiO<sub>2</sub> and UV-Ozone treatment. The hysteresis effect has been defined as normal, free and inverted.

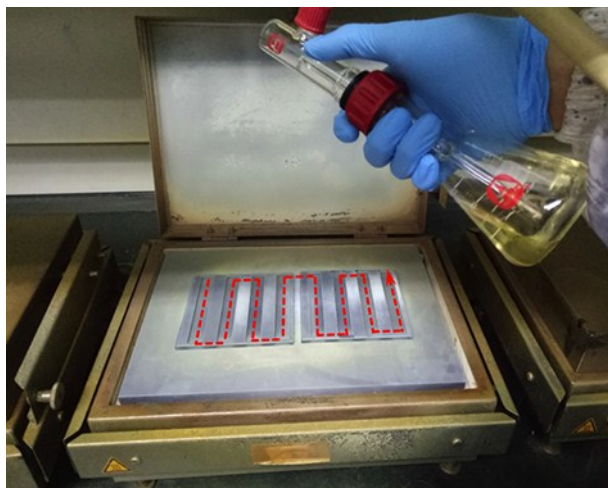
Condition	c-TiO <sub>2</sub> × 1	c-TiO <sub>2</sub> × 2	c-TiO <sub>2</sub> × 3	c-TiO <sub>2</sub> × 4
UV-Ozone 0 min	Normal	Normal	Normal	Normal
UV-Ozone 2.5 min	Inverted	Free	Normal	Normal
UV-Ozone 10 min	Inverted	Inverted	Normal	Normal
UV-Ozone 30 min	Inverted	Inverted	Free	Normal

**Table S2.** Series resistance and shunt resistance of hysteresis-normal, hysteresis-free, and hysteresis-inverted devices measured at different scan directions and scan rates ( $R_S$ :  $\Omega$  cm<sup>2</sup>;  $R_{SH}$ : k $\Omega$  cm<sup>2</sup>).

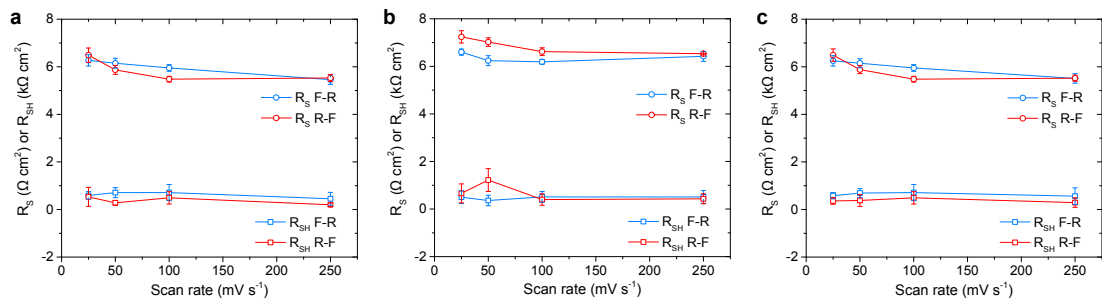
	F-R scan		R-F scan		F-R scan		R-F scan		F-R scan		R-F scan		F-R scan		R-F scan	
	25 mV s <sup>-1</sup>				50 mV s <sup>-1</sup>				100 mV s <sup>-1</sup>				250 mV s <sup>-1</sup>			
	$R_S$	$R_{SH}$	$R_S$	$R_{SH}$	$R_S$	$R_{SH}$	$R_S$	$R_{SH}$	$R_S$	$R_{SH}$	$R_S$	$R_{SH}$	$R_S$	$R_{SH}$	$R_S$	$R_{SH}$
Normal	6.27±	0.59±	6.49±	0.53±	6.15±	0.71±	5.87±	0.28±	5.95±	0.71±	5.48±	0.49±	5.46±	0.45±	5.53±	0.20±
	0.24	0.16	0.30	0.40	0.21	0.21	0.19	0.10	0.14	0.34	0.12	0.26	0.20	0.27	0.15	0.07
Free	6.60±	0.50±	7.24±	0.66±	6.24±	0.36±	7.02±	1.22±	6.19±	0.51±	6.62±	0.4±0.	6.42±	0.51±	6.53±	0.43±
	0.13	0.27	0.26	0.4	0.21	0.22	0.18	0.48	0.1	0.23	0.16	24	0.21	0.27	0.02	0.21
Inverted	6.25±	0.58±	6.49±	0.36±	6.15±	0.69±	5.88±	0.38±	5.95±	0.71±	5.48±	0.49±	5.51±	0.56±	5.52±	0.29±
	0.22	0.13	0.26	0.14	0.19	0.19	0.17	0.25	0.14	0.34	0.12	0.26	0.20	0.35	0.13	0.20

**Table S3 Fitting decay times of time-resolved photoluminescence (TRPL) spectra.** The semi-devices were fabricated as FTO/c-TiO<sub>2</sub>/m-TiO<sub>2</sub>/ZrO<sub>2</sub>/Perovskite, and the c-TiO<sub>2</sub> layers were sprayed with 1-4 cycles.

c-TiO <sub>2</sub> cycle	$\tau_1$ (ns)	$\tau_2$ (ns)
1	1.12	33.91
	1.16	36.48
	1.10	36.89
2	2.16	51.29
	1.29	37.90
	1.11	38.39
3	1.23	39.95
	1.19	37.68
	1.18	37.58
4	1.46	40.05
	1.39	39.57
	1.21	40.66

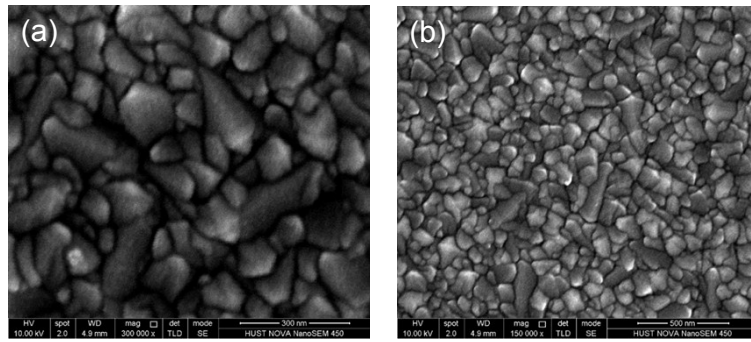


**Fig. S1** The spraying deposition process of the compact-TiO<sub>2</sub> (c-TiO<sub>2</sub>) layer. The sprayer is purchased from Sigma-Aldrich, and the carrier gas is N<sub>2</sub> with a flow rate of ~10 ml/s.

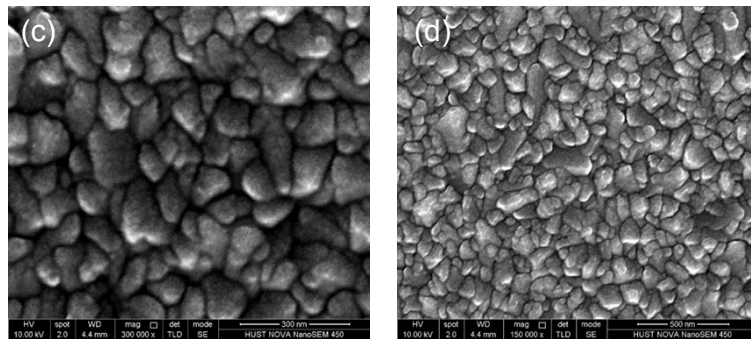


**Fig. S2** The dependence of  $R_S$  and  $R_{SH}$  on scan rates for hysteresis-normal, hysteresis-free and hysteresis-inverted devices.

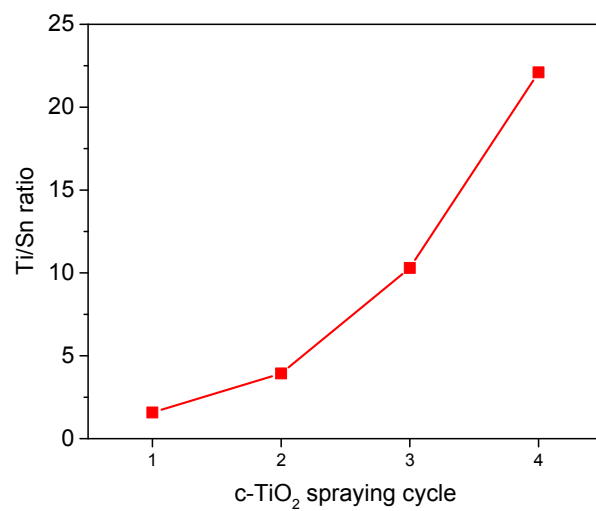
Bare FTO



c-TiO<sub>2</sub> sprayed FTO

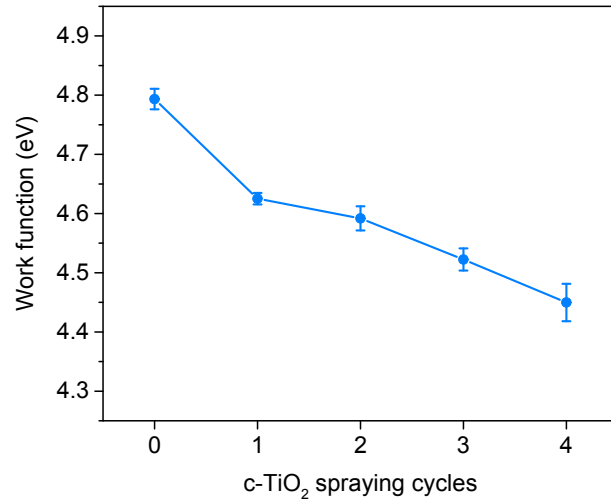


**Fig. S3** Surface morphology characterizations. The SEM images of the bare FTO substrate (a, b) and c-TiO<sub>2</sub> sprayed (two cycles) FTO substrate (c, d).

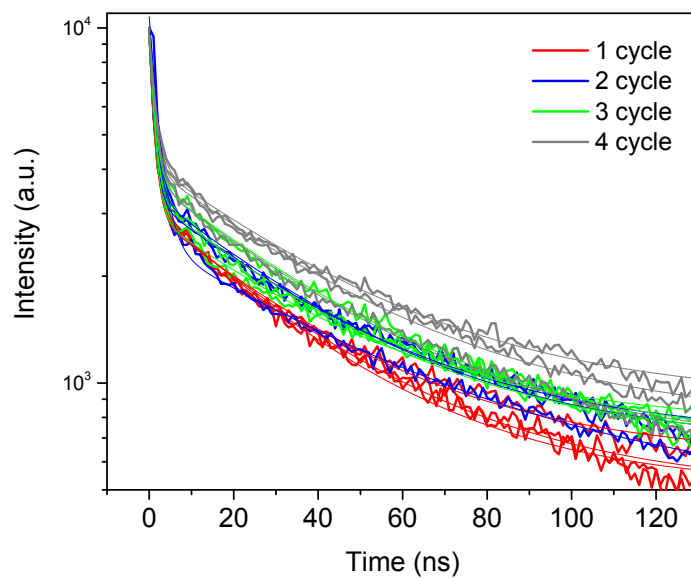


**Fig. S4** XPS results of FTO substrates sprayed with 1-4 cycles of c-TiO<sub>2</sub> layer. The measurements were performed using the same accumulation time, and the Ti and Sn peak areas are compared.

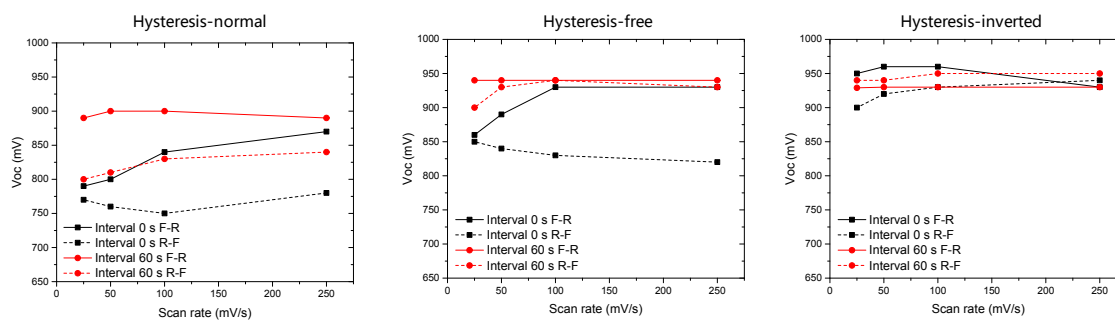




**Fig. S5** Work function of FTO substrates sprayed with 0-4 cycle of c-TiO<sub>2</sub> layer (Error bars represent *s.d.* calculated from five values obtained with the same testing parameters).



**Fig. S6** Time-resolved photoluminescence (TRPL) spectra of FTO/c-TiO<sub>2</sub>/m-TiO<sub>2</sub>/ZrO<sub>2</sub>/Perovskite semi-devices. The c-TiO<sub>2</sub> layers were sprayed with 1-4 cycles. For each spraying cycle, three samples were prepared and characterized.



**Fig. S7** Dependence of  $V_{OC}$  on scanning rates. The hysteresis-normal, -free and -inverted devices were continuously scanned with an interval of 0 s or discontinuously scanned with an interval of 60 s at 250  $\text{mV s}^{-1}$ , 100  $\text{mV s}^{-1}$ , 50  $\text{mV s}^{-1}$  and 25  $\text{mV s}^{-1}$  firstly in F-R direction, and then in R-F direction.

## Reference

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3. A. Mei, X. Li, L. Liu, Z. Ku, T. Liu, Y. Rong, M. Xu, M. Hu, J. Chen, Y. Yang, M. Grätzel and H. Han, *Science*, 2014, **345**, 295-298.